

2014 DOE OE Energy Storage Program Peer Review

60kW Inverter with Built-In Isolation Using GaN Devices (SBIR Phase I – DOE Energy Storage Program, Dr. Imre Gyuk and Technical POC Dr. Stan Atcitty, Sandia National Laboratories)

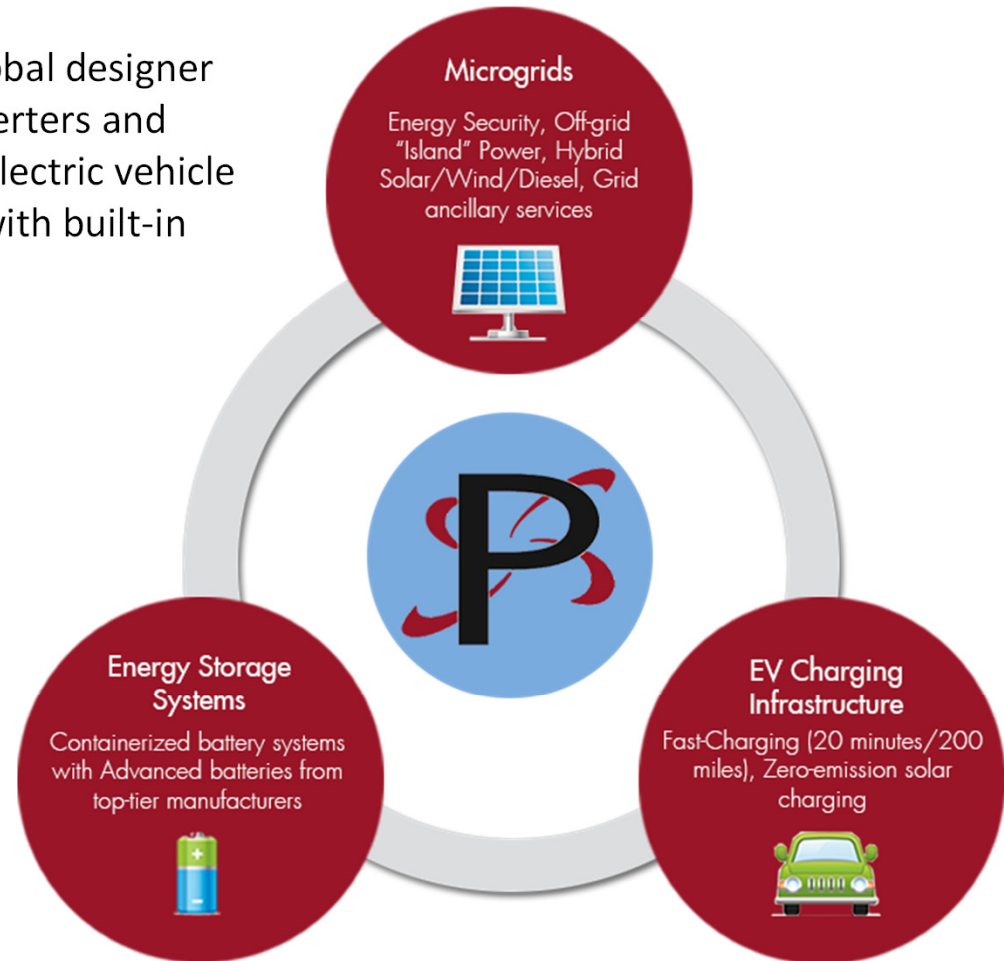
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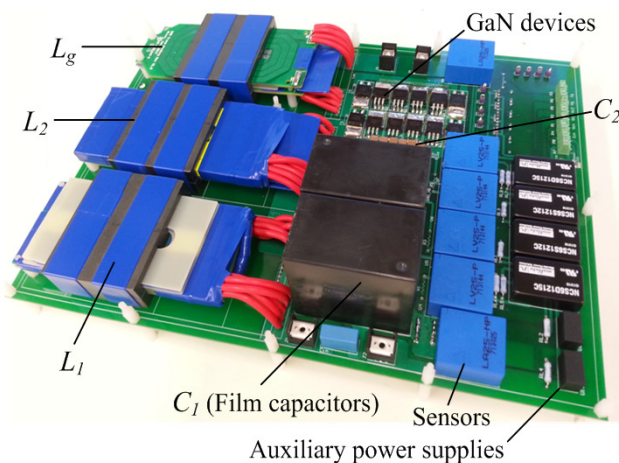
Project Team: PPS

Princeton Power Systems is a leading global designer and manufacturer of bi-directional converters and energy storage systems for microgrids, electric vehicle (EV) charging, and advanced batteries, with built-in functions for Smart Grid Services.

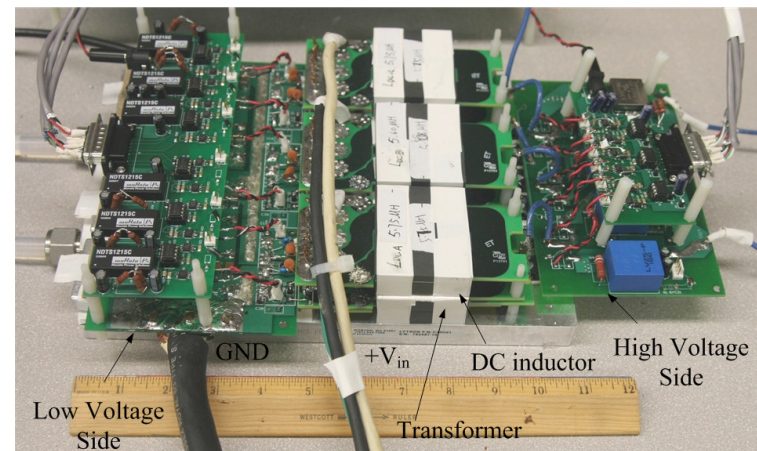


Project Team: Florida State University/PE Group

FSU/PE group has rich experience about WBG devices application in grid-connected PV converters. The group has successfully developed GaN based PV Module-Integrated Converter (MIC) and SiC based high power PV converters for grid-interactive application to achieve high power density and high power efficiency. The high frequency operation performance of GaN and SiC devices has been investigated and evaluated.



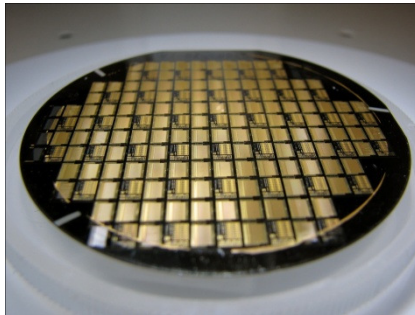
GaN based Module-integrated PV converter



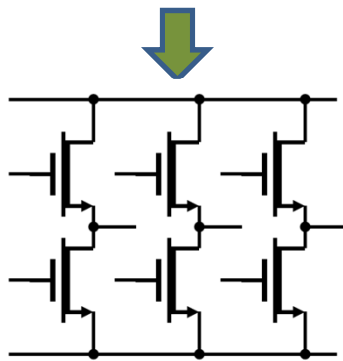
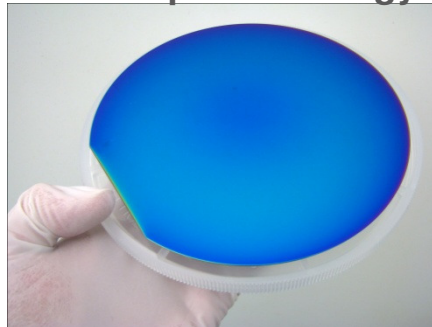
Three-port 5kW grid-tie PV converter

Project Team: Transphorm – GaN Technology

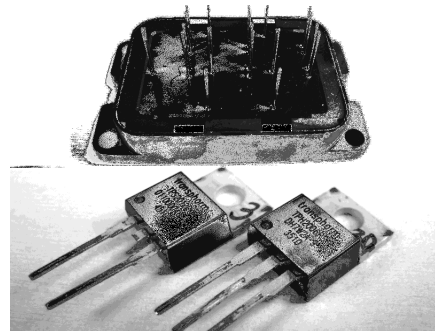
Device eng & Fab



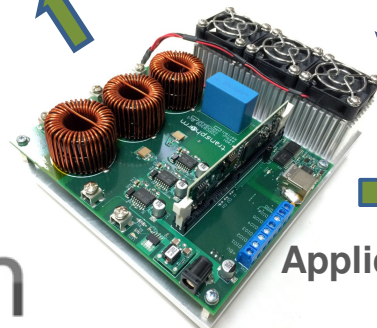
GaN Epi Technology



Product design



Discretes & Modules



Application demos

Motor Drives

Power Supplies

Solar Inverters

EV Motor Inverters

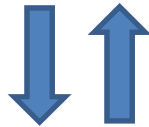
transphorm

 **PRINCETON
POWER SYSTEMS**
Clean Power Made Simple™

Why are we doing this ?

○ Technology Development:

- Demonstrate use of Wide-band-gap devices in a real application
- Devices need to be used to become cheaper



Device need to become cheaper to be used

○ Product / Application Development

- Reduce cost & size of grid-tied energy storage installations by eliminating bulky grid-side isolation transformers
- Improve efficiency
- Reduce noise (by switching at frequencies outside the audible range)

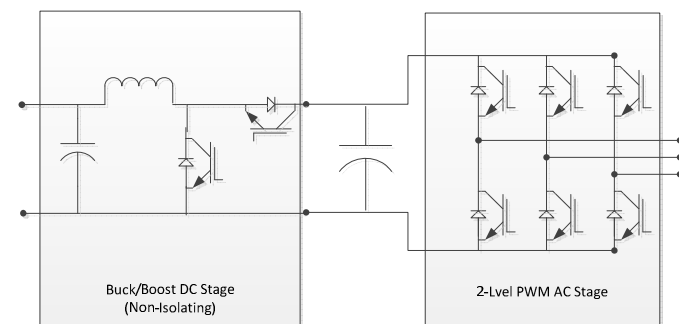


Project Steps

- **Phase I : Design 60kW inverter for grid-tied storage applications**
 - Base design on existing PPS 100kW inverter
 - Incorporate DC side isolation by using Dual-Active-Bridges (DAB) using GaN devices
 - Demonstrate DAB functionality
- **Phase II : Build prototype inverter**
 - Modify an existing GTIB inverter with design from Phase I
 - Demonstrate inverter functionality

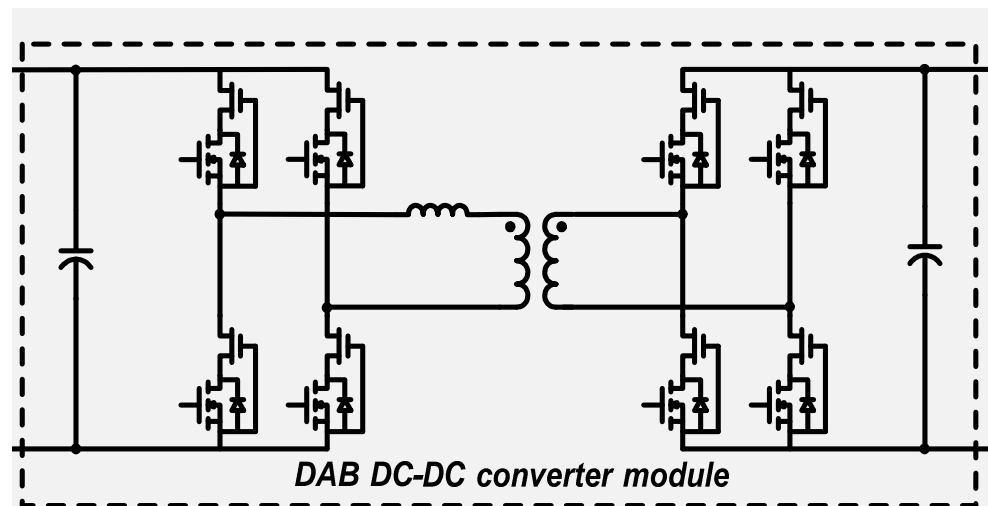
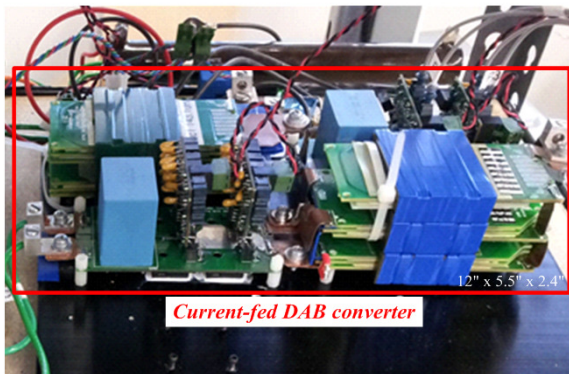
PPS Grid-Tied Inverter (GTIB-100)

- **100kW grid-tied inverter**
 - Buck/boost DC stage
 - 2-level PWM AC stage
 - 6.5kHz switching frequency
- **Proven technology, used in a number of grid-tied energy storage applications**
 - 'Two-Ups' for Tesla
 - WPD project with GE in the UK
- **No internal isolation -> typically requires external transformer**



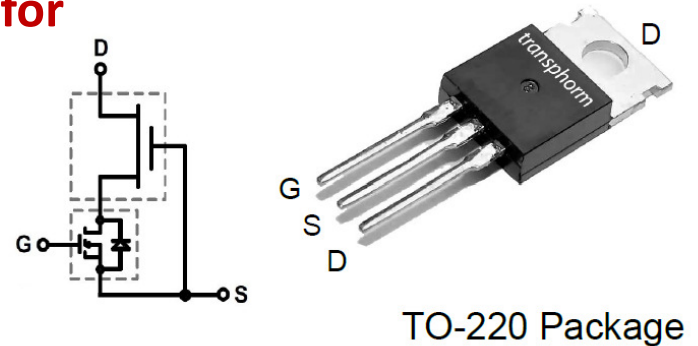
Dual-Active Bridge DC-DC Converter (FSU)

- High-frequency switching (proven in lab at FSU)
 - Drastically decreases size of DC port components
- Built-in galvanic isolation
 - Eliminates grid-side transformer, increasing overall system power density



High Voltage GaN HEMT

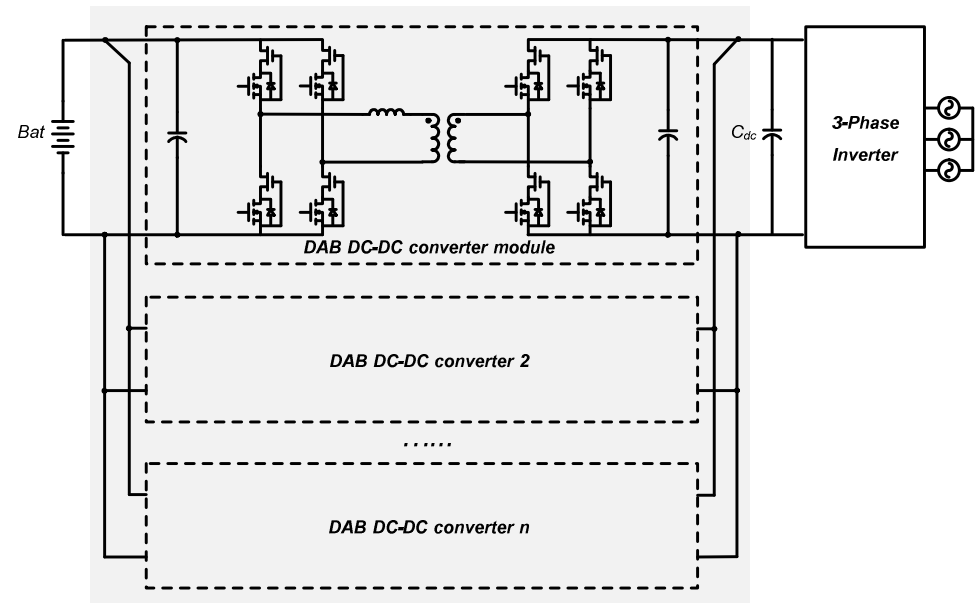
- High Switching Frequency : 10x of Si devices for smaller Q_g , C_{oss} & Q_{rr}
- Low R_{ds_on} : $V_B^2/R_{on}=5000$ (40 for Si)
- High temperature operation > 200 C
- Third quadrant operation: Eliminates free-wheeling diode
- Normally-off operation: Safe for high voltage/power



| Ron | Vds,max | I _{max} (pulse) | I _{max} (CW) |
|-----------------|----------------|--------------------------|-----------------------|
| mohm | V | A | A |
| 30 | 900 | 240 | 70 |
| R _{th} | Q _g | Q _{oss} | Q _{rr} |
| °C/W | nC | nC | uC |
| 0.2 | 25 | 320 | 0.35 |
| *Per switch | | | |

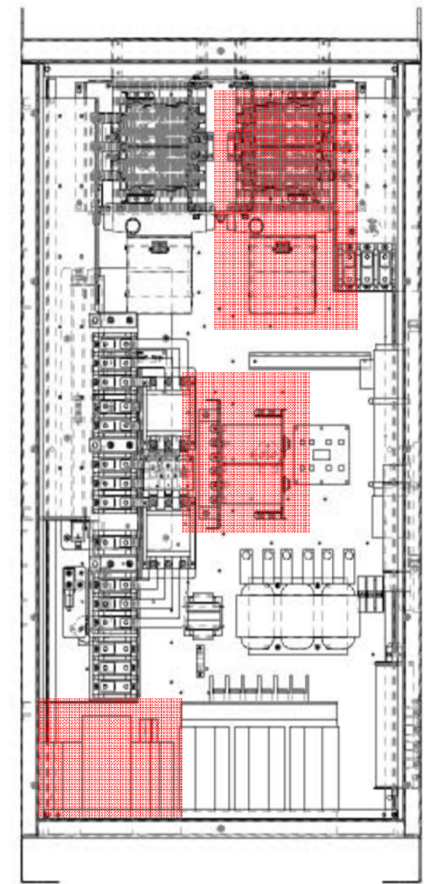
Target System Architecture

- Keep existing AC stage of GTIB inverter
 - Focusing on main project aspect
- DC stage will consist of multiple DAB converters
 - Allows interleaving, to reduce current ripple
 - Avoids challenges from having to parallel GaN devices



Design Goals

- DC-DC Stage Efficiency $\geq 98\%$
- Increase overall power density of installation by 40%
- Reduce overall system cost by 20%
 - Eliminate grid-side isolation transformer (-20% total system cost)
 - Reduce cost of reactive components for DC side by estimated 50% (-6% total system cost)



Removable DC port
Components

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Thank you

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